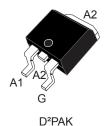


8 A - 800 V logic level T-series Triac in D²PAK









Product status link

T810T-8G

Product summary			
I _{T(RMS)}	8 A		
V_{DRM}/V_{RRM}	800 V		
V _{DSM} /V _{RSM}	900 V		
I _{GT}	10 mA		

Features

- 150 °C maximum junction temperature
- · Three quadrants
- · High commutation on resistive loads
- Surge capability V_{DSM}, V_{RSM} = 900 V
- · Benefits:
 - Easy direct control by MCU thanks to low 10 mA I_{GT}
 - Increase of thermal margin due to extended working T_i up to 150 °C

Applications

- · General purpose AC line load switching
- · Small home appliances with resistive loads
- Hybrid relays
- · Inrush current limiting circuits
- · Overvoltage crowbar protection

Description

The SMD T810T-8G Triac can be used for the on/off or phase angle control function in general purpose AC switching with resistive loads. A Logic level T-series Triac, the T810T-8G can be controlled directly from an MCU with a simplified circuit.

T-series triacs are optimized for high EMI constraints. The surface mount D²PAK package enables compact SMT designs for automated manufacturing.

D²PAK's molding compound resin is halogen-free and meets UL94 flammability standard level V0.

Package environmentally friendly ECOPACK2 graded (RoHS and Halogen Free compliance).



1 Characteristics

Table 1. Absolute maximum ratings (limiting values), $T_j = 25$ °C unless otherwise specified

Symbol	Parameter	Value	Unit		
I _{T(RMS)}	RMS on-state current (full sine wave)	T _c = 131 °C	8	Α	
l	Non repetitive surge peak on-state current (T_j initial = 25 °C) $t = 2$		T _j = 25 °C	63	^
I _{TSM}			1j = 25 C	60	Α
I ² t	l ² t value for fusing	t _p = 10 ms	T _j = 25 °C	24	A ² s
dl/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$, $tr \le 100 \text{ ns}$	f = 50 Hz	T _j = 25 °C	100	A/µs
\/	5	T _j = 125 °C	800	V	
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage	T _j = 150 °C	600	V	
V _{DSM} /V _{RSM}	Non Repetitive peak off-state voltage t _p = 10 ms		T _j = 25 °C	900	V
I _{GM}	Peak gate current	4 - 20	T _j = 150 °C	4	Α
V_{GM}	Peak Gate Voltage		T _j = 150 °C	5	V
P _{G(AV)}	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$				W
T _{stg}	Storage junction temperature range				°C
T _j	Operating junction temperature range				°C

Table 2. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Test conditions		Quadrants; T _j		Value	Unit
I _{GT} ⁽¹⁾	$V_D = 12 \text{ V, R}_1 = 30 \Omega$		1 - 11 - 111	Min.	0.5	m A
'GT\'	VD = 12 V, 1\(\(\bar{\}\) = 30 \(\bar{\}\)2		1 - 11 - 111	Max.	10	mA
V_{GT}	$V_D = 12 \text{ V}, R_L = 30 \Omega$		1 - 11 - 111	Max.	1.3	V
V_{GD}	V_D = 800 V, R_L = 3.3 k Ω	T _j = 125 °C	1 - 11 - 111	Min.	0.2	V
ال	I _G = 1.2 x I _{GT}		1 - 111	Max.	20	mA
"L	I _G = 1.2 x I _{GT}	II	Max.	25	mA	
I _H ⁽²⁾	I _T = 500 mA, gate open		Max.	15	mA	
dV/dt (2)	V _D = 536 V, gate open	T _j = 125 °C	Min.	250	V/µs	
uv/ut (=)	V _D = 402 V, gate open	T _j = 150 °C	Min.	170	V/µs	
	(dV/dt)c = 0.1 V/µs	T _j = 125 °C	Min	6	A/ms	
(d)(dt)a (2)	(αν/αι)c – σ. τ ν/μs	T _j = 150 °C	Min.	4.2		
(dl/dt)c (2)	(dV/dt)c = 10 V/µs		T _j = 125 °C	Min.	3.2	Δ /
	(αν/αι)ς – το ν/μς	T _j = 150 °C	IVIIII.	1.4	A/ms	

^{1.} Minimum I_{GT} is guaranteed at 5% of I_{GT} max

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^{2.} For both polarities of A2 referenced to A1.



Table 3. Static characteristics

Symbol	Test conditions	Tj		Value	Unit
V _{TM} ⁽¹⁾	I _T = 11.3 A, t _p = 380 μs	25 °C	Max.	1.55	V
V _{TO} ⁽¹⁾	Threshold on-state voltage	150 °C	Max.	0.85	V
R _D ⁽¹⁾	R _D ⁽¹⁾ Dynamic resistance		Max.	57	mΩ
	V _{DRM} = V _{RRM} = 800 V	25 °C	Max.	5	μA
I _{DRM} /I _{RRM}	VDRM - VRRM - 000 V	125°C	IVIAX.	0.8	mA
	V _{DRM} = V _{RRM} = 600 V	150 °C	Max.	2.4	mA

^{1.} For both polarities of A2 referenced to A1.

Table 4. Thermal resistance

Symbol	Parameter	Value	Unit	
R _{th(j-c)}	Junction to case (AC)	Max.	1.9	°C/W
R _{th(j-a)}	Junction to ambient (AC) for S _{Cu} = 2 cm ²	Тур.	45	C/VV

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1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current

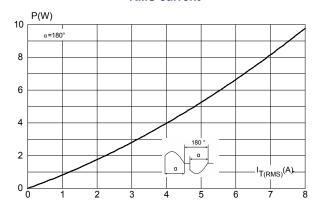


Figure 3. On-state RMS current versus ambient temperature (free air convection)

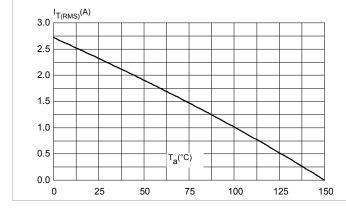


Figure 4. Relative variation of thermal impedance versus pulse duration

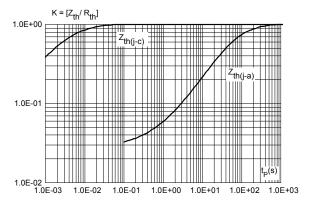


Figure 5. On-state characteristics (maximum values)

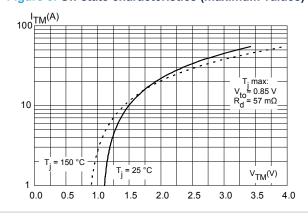
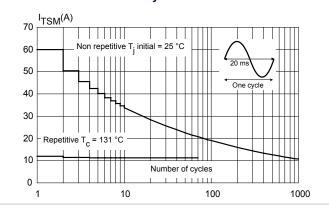


Figure 6. Surge peak on-state current versus number of cycles



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Figure 7. Non repetitive surge peak on-state current

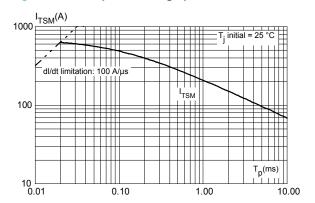


Figure 8. Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)

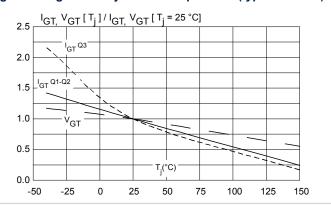


Figure 9. Relative variation of critical rate of decrease of main current versus junction temperature (typical values)

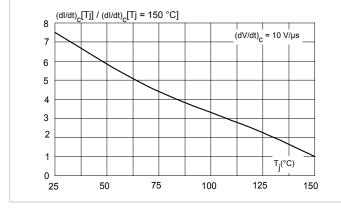


Figure 10. Relative variation of holding current and latching current versus junction temperature (typical values)

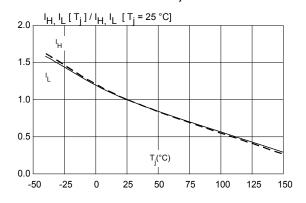


Figure 11. Relative variation of critical rate of decrease of main current (dl/dt)C versus reapplied (dl/dt)C (maximum values)

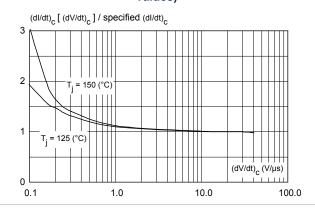
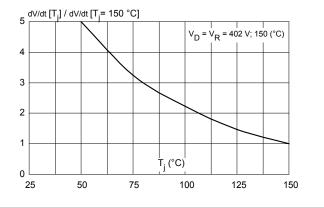


Figure 12. Relative variation of static dV/dt immunity versus junction temperature (typical values)



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Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)

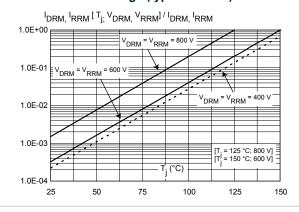
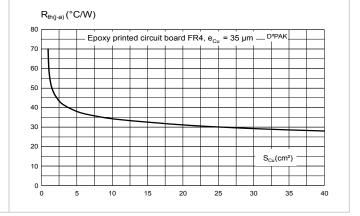


Figure 14. Thermal resistance junction to ambient versus copper surface under tab



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 D²PAK package information

- ECOPACK2 compliant
- · Lead-free package leads finishing
- Molding compound resin is halogen-free and meets UL standard level V0

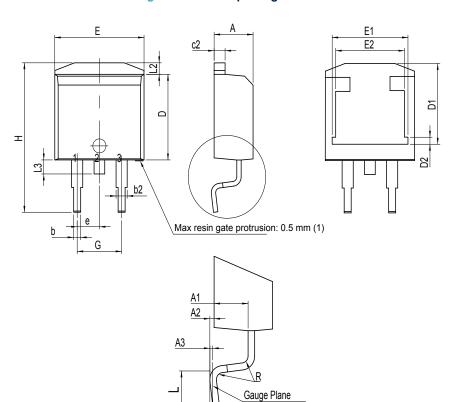


Figure 15. D²PAK package outline

(1) Resin gate is accepted in each of position shown on the drawing, or their symmetrical.

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Table 5. D²PAK package mechanical data

	Dimensions						
Ref.		Millimeters		Inches ⁽¹⁾			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.30		4.60	0.1693		0.1811	
A1	2.49		2.69	0.0980		0.1059	
A2	0.03		0.23	0.0012		0.0091	
A3		0.25			0.0098		
b	0.70		0.93	0.0276		0.0366	
b2	1.25		1.7	0.0492		0.0669	
С	0.45		0.60	0.0177		0.0236	
c2	1.21		1.36	0.0476		0.0535	
D	8.95		9.35	0.3524		0.3681	
D1	7.50		8.00	0.2953		0.3150	
D2	1.30		1.70	0.0512		0.0669	
е		2.54			0.1		
E	10.00		10.28	0.3937		0.4047	
E1	8.30		8.70	0.3268		0.3425	
E2	6.85		7.25	0.2697		0.2854	
G	4.88		5.28	0.1921		0.2079	
Н	15		15.85	0.5906		0.6240	
L	1.78		2.28	0.0701		0.0898	
L2	1.19		1.40	0.0468		0.0551	
L3	1.40		1.75	0.0551		0.0689	
R		0.40			0.0157		
V2 ⁽²⁾	0°		8°	0°		8°	

^{1.} Dimensions in inches are given for reference only

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^{2.} Degrees





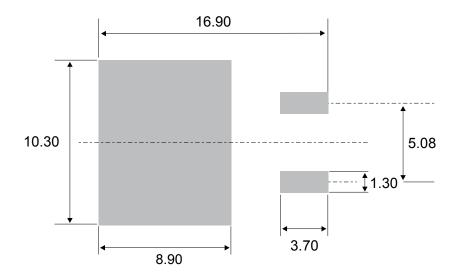
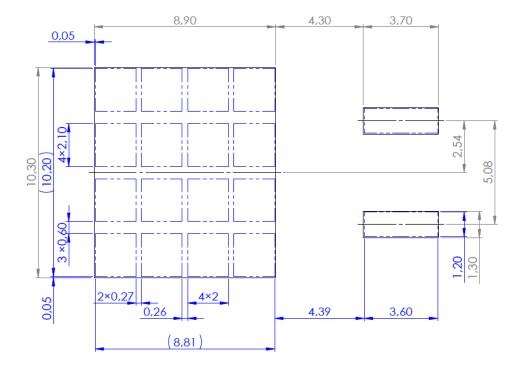


Figure 17. D²PAK stencil definitions(dimensions are in mm)



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3 Ordering information

Figure 18. Ordering information scheme

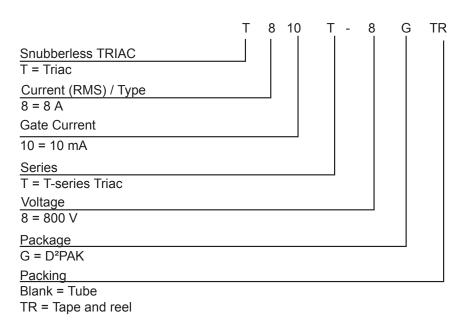


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T810T-8G-TR	T810T-8G	D²PAK 1.6 a	1000	Tape and reel	
T810T-8G	10101-00	DIFAR	1.6 g	50	Tube

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Revision history

Table 7. Document revision history

Date	Version	Changes
04-Jun-2020	1	Initial release.
20-Oct-2020	2	Updated Table 5.



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